SEMICONDUCTOR

SURFACE MOUNT FAST SWITCHING DIODE

ÎG

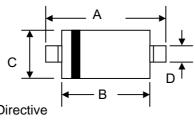
Data Sheet 4200, Rev. -

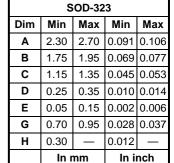
Green Products

1N4148WS-G

Features

- High Conductance
- Fast Switching Speed
- Surface Mount Package Ideally Suited for Automatic Insertion
- For General Purpose Switching Application
- Plastic Material UL Recognition Flammability Classification 94V-O
- Green Products in Compliance with the RoHS Directive





Mechanical Data

- Case: SOD-323, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.004 grams (approx.)
- Marking: A2

Maximum Ratings @TA=25°C unless otherwise specified

Characteristic	Symbol	1N4148WS-G	Unit
Non-Repetitive Peak Reverse Voltage	VRM	100	V
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	VRRM VRWM VR	75	V
RMS Reverse Voltage	VR(RMS)	53	V
Forward Continuous Current (Note 1)	lғм	300	mA
Average Rectified Output Current (Note 1)	lo	150	mA
Non-Repetitive Peak Forward Surge Current @ t = 1.0µs @ t = 1.0s	IFSM	2.0 1.0	А
Power Dissipation (Note 1)	Pd	200	mW
Typical Thermal Resistance, Junction to Ambient Air (Note 1)	$R_{ heta}$ JA	625	K/W
Operating and Storage Temperature Range	Тj, Tsтg	-65 to +150	°C

Electrical Characteristics @TA=25°C unless otherwise specified

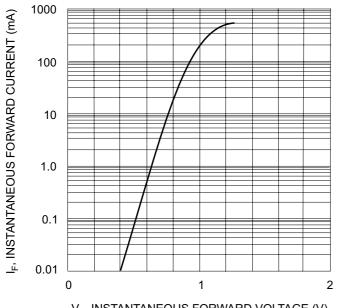
Characteristic		Symbol	1N4148WS-G	Unit
Forward Voltage Drop	@ IF = 10mA	VFM	1.0	V
Peak Reverse Leakage Current	@ VR = 75V	IRM	2.5	μA
Junction Capacitance (VR = 0V DC, f = 1.0MHz)		Cj	2.0	pF
Reverse Recovery Time (Note 2)		trr	4.0	nS

Note: 1. Valid provided that terminals are kept at ambient temperature.

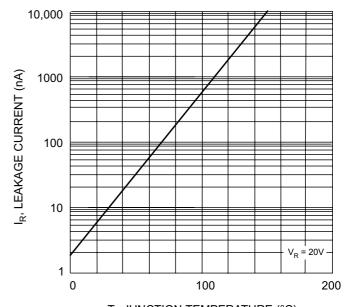
2. Measured with IF = IR = 10mA, IRR = 0.1 x IR, RL = 100Ω .

Data Sheet 4200, Rev. -

Green Products



V_F, INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 1 Forward Characteristics



T_j, JUNCTION TEMPERATURE (°C) Fig. 2 Leakage Current vs Junction Temperature

SURFACE MOUNT FAST SITCHNG DIODE

Data Sheet 4200, Rev. -

Green Products

DISCLAIMER:

- 1- The information given herein, including the specifications and dimensions, is subject to change without prior not ice to improve product characteristics. Before ordering, purchasers are advised to contact the Sensitron Semiconductor sales department for the latest version of the datasheet(s).
- 2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.
- 3- In no event shall Sensitron Semiconductor be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). Sensitron Semiconductor assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets. 4- In no event shall Sensitron Semiconductor be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.
- 5- No license is granted by the datasheet(s) under any patents or other rights of any third party or Sensitron Semiconductor.
- 6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed writ ten permission of Sensitron Semiconductor.
- 7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations.